## NSN 5962-01-016-2684

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Body Length:
Between 1.155 inches and 1.215 inches
Body Width:
Between 0.500 inches and 0.560 inches
Body Height:
Between 0.075 inches and 0.135 inches
Maximum Power Dissipation Rating:
575.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-55.0/+165.0 degrees celsius
Features Provided:
Monolithic and hermetically sealed and bipolar and medium speed and programmable and w/open collector
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
9 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-1.5 volts power source and 5.5 volts power source
Time Rating Per Chacteristic:
140.00 nanoseconds propagation delay time, low to high level output and 140.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
<del></del>
Demilitarization:
Yes - demil/mli
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